



ZHCS283C-JULY 2006-REVISED MARCH 2009

具有 600mA 开关的 90% 高效同步升压转换器

查询样品: TPS61070, TPS61071, TPS61072, TPS61073

特性

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- 90% 高效同步升压转换器
 - 在 3.3 V 电压下可提供 75 mA 输出电流 (采用 0.9 V 输入时)
 - 在 3.3 V 电压下可提供 150 mA 输出电流 (采用 1.8 V 输入时)
- 器件静态电流: **19 µA**(典型值)
- 输入电压范围: 0.9V 至 5.5V
- 可调输出电压高达 5.5 V
- 可提供省电模式版本,以 改善低输出功率时的效率
- 停机期间负载断开
- 过温保护
- 小型 6 引脚 Thin SOT23 封装

应用

- 所有一节、两节和三节碱性、镍镉或镍氢电池供电型产品或单节锂
 电池供电型产品
- 便携式音频播放器
- PDA

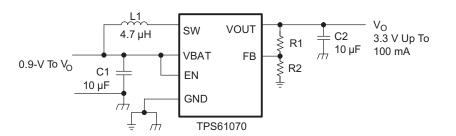
ÆΛ

- 蜂窝电话
- 个人医疗产品
- 白光 **LED** 照明

说明

TPS6107x 器件为那些采用单节、双节或三节碱性电 池、镍镉电池或镍氢电池供电的产品或单节锂离子电池 或锂聚合物电池供电的产品提供了一款电源解决方案。 当采用单节碱性电池时,输出电流可变至高达 75 mA,并将电池放电到低至 0.9 V。它还可用于依靠一 个3.3V 电压轨或单节锂离子电池产生 5V/200mA 输 出。升压转换器基于一个采用同步整流器的固定频 率、脉宽调制 (PWM) 控制器,旨在实现最高的效率。 在低负载电流条件下,TPS61070 和 TPS61073 进入 省电模式,以在宽负载电流范围内保持高效率。在 TPS61071 和 TPS61072 中,省电模式被停用,因而 强制转换器在某个固定的开关频率条件下操作。升压 开关中的最大峰值电流通常被限制为 600 mA。

TPS6107x 的输出电压由一个外部电阻分压器来设置。可以停用转换器以最大限度地减少电池消耗。 在停机期间,将负载与电池完全断开。 该器件采用 6 引脚薄型 SOT23 封装 (DDC)。



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

T _A	OUTPUT VOLTAGE DC/DC	POWER- SAVE MODE	OPERATING FREQUENCY EN THRESHOLD REFERENCE VOLTAGE		PACKAGE MARKING	PACKAGE	PART NUMBER ⁽²⁾					
	Adjustable	Enabled	1200 kHz	VBAT	AUH		TPS61070DDC					
- 40°C to	Adjustable	Disabled	1200 kHz	VBAT	AUJ	6-Pin	TPS61071DDC					
85°C	Adjustable	Disabled	600 kHz	VBAT	BUM	TSOT23	TPS61072DDC					
	Adjustable	Enabled	1200 kHz	1.8 V Logic	BUN		TPS61073DDC					

AVAILABLE OUTPUT VOLTAGE OPTIONS⁽¹⁾

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) The DDC package is available taped and reeled. Add R suffix to device type (e.g., TPS61070DDCR) to order quantities of 3000 devices per reel. Add T suffix to device type (e.g., TPS61070DDCT) to order quantities of 250 devices per reel.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	TPS6107x
Input voltage range on SW, VOUT, VBAT, EN, FB	-0.3 V to 7 V
Operating virtual junction temperature range, T_J	-40°C to 150°C
Storage temperature range T _{stg}	-65°C to 150°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATINGS TABLE⁽¹⁾

PACKAGE		THERMAL RESISTANCE	POWER RATING	DERATING FACTOR	
	Θ_{JA}	Θ _{JB}	Θ ^{IC}	T _A ≤ 25°C	ABOVE T _A = 25°C
DDC	130 °C/W	27 °C/W	41 °C/W	769 mW	7.7 mW/°C

(1) This thermal data is based on assembly of the device on a JEDEC high K board. Exceeding the maximum junction temperature will force the device into thermal shutdown.

RECOMMENDED OPERATING CONDITIONS

	MIN	NOM MAX	UNIT
Supply voltage at VBAT, VI (TPS61070, TPS61071, TPS61072)	0.9	5.5	V
Supply voltage at VBAT, VI (TPS61073)	2.3	5.5	V
Operating free air temperature range, T _A	-40	85	°C
Operating virtual junction temperature range, T _J	-40	125	°C



ELECTRICAL CHARACTERISTICS

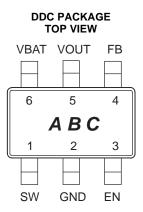
over recommended free-air temperature range and over recommended input voltage range (typical at an ambient temperature range of 25°C) (unless otherwise noted)

DC/DC	STAGE						
	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Minimum input voltage rar start-up (TPS61070, TPS61071, T	0	R _L = 270 Ω		1.1	1.2	
VI	Minimum input voltage rar start-up (TPS61073)	nge for	R _L = 270 Ω			2.3	V
	Input voltage range, after (TPS61070, TPS61071, T		$T_A = 25^{\circ}C$	0.9		5.5	
	Input voltage range, after (TPS61073)	start-up		2.3		5.5	
Vo	Output voltage range (TPS TPS61071, TPS61072)	S61070,		1.8		5.5	V
	Output voltage range (TPS	S61073)		2.3		5.5	
V _(FB)	Feedback voltage			495	500	505	mV
f	Oscillator frequency (TPS) TPS61071, TPS61073)	61070,		960	1200	1440	kHz
	Oscillator frequency (TPS61072)			480	600	720	
I _(SW)	Switch current limit		VOUT= 3.3 V	500	600	700	mA
	Start-up current limit				$0.5 \times I_{SW}$		mA
	Boost switch-on resistance	e	VOUT= 3.3 V		480		mΩ
	Rectifying switch-on resist	ance	VOUT= 3.3 V		600		mΩ
	Total accuracy (including load regulation)	ine and				3%	
	Line regulation					1%	
	Load regulation					1%	
	Quiescent current	VBAT	I _O = 0 mA, V _(EN) = VBAT = 1.2 V,		0.5	1	μA
	(TPS61070, TPS61071, TPS61072)	VOUT	$VOUT = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$		19	30	μA
	Quiescent current	VBAT	I _O = 0 mA, V _(EN) = 1.8 V, VBAT = 2.4 V,		1	1.5	μA
	(TPS61073)	VOUT	$VOUT = 5 V, T_A = 25^{\circ}C$		30	50	μA
	Shutdown current (TPS61 TPS61071, TPS61072)	070,	V _(EN) = 0 V, VBAT = 1.2 V, T _A = 25°C		0.05	0.5	μA
	Shutdown current (TPS61	073)	V _(EN) = 0 V, VBAT = 3.6 V, T _A = 25°C		0.05	1.5	μA

CONTRO	L STAGE					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _(UVLO)	Undervoltage lockout threshold	V _(BAT) voltage decreasing		0.8		V
V _{IL}	EN input low voltage (TPS61070, TPS61071, TPS61072)				0.2 × VBAT	
12	EN input low voltage (TPS61073)				0.4	V
VIH	EN input high voltage (TPS61070, TPS61071, TPS61072)		0.8 × VBAT			
	EN input high voltage (TPS61073)		1.2			V
	EN input current (TPS61070, TPS61071, TPS61072)	Clamped on GND or VBAT		0.01	0.1	μA
	EN input current (TPS61073)	Clamped on GND or VBAT		0.01	0.3	μA
	Overtemperature protection			140		°C
	Overtemperature hysteresis			20		°C



PIN ASSIGNMENTS

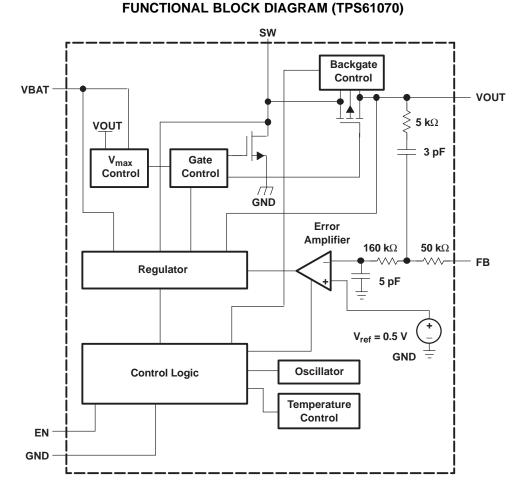


Terminal Functions

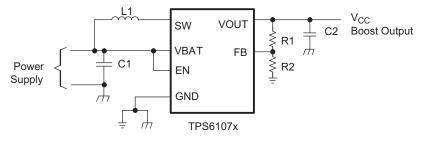
TERMINAL		I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
EN	3	I	Enable input (1/VBAT enabled, 0/GND disabled)
FB	4	I	Voltage feedback for programming the output voltage
GND	2		IC ground connection for logic and power
SW	1	I	Boost and rectifying switch input
VBAT	6	I	Supply voltage
VOUT	5	0	Boost converter output



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Parameter Measurement Information



List of Components: U1 = TPS61070DDC L1 = 4.7 μ H Wurth Elektronik 744031004 C1 = 2 x 4.7 μ F, 0603, X7R/X5R Ceramic C2 = 4 x 4.7 μ F, 0603, X7R/X5R Ceramic

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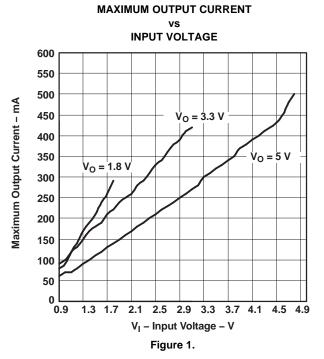
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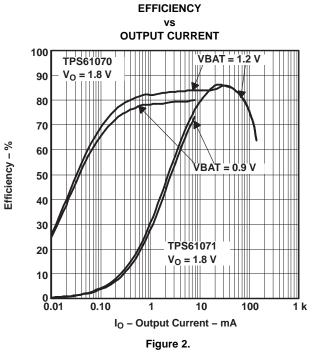
TYPICAL CHARACTERISTICS

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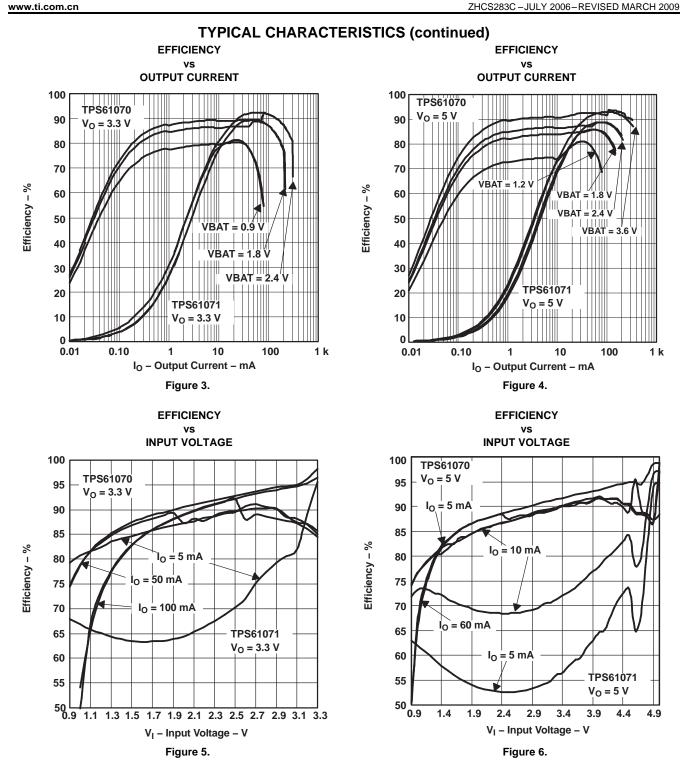
TYPICAL CHARACTERISTICS



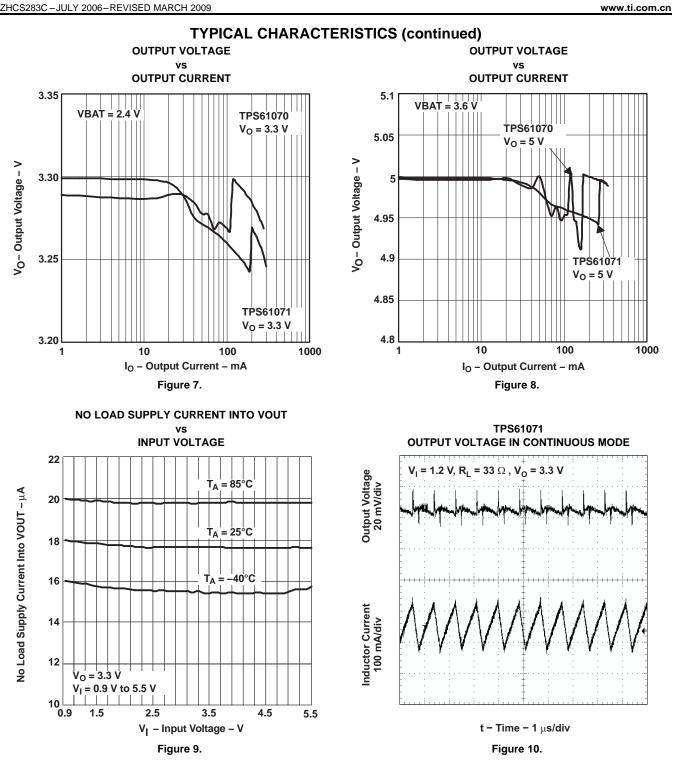




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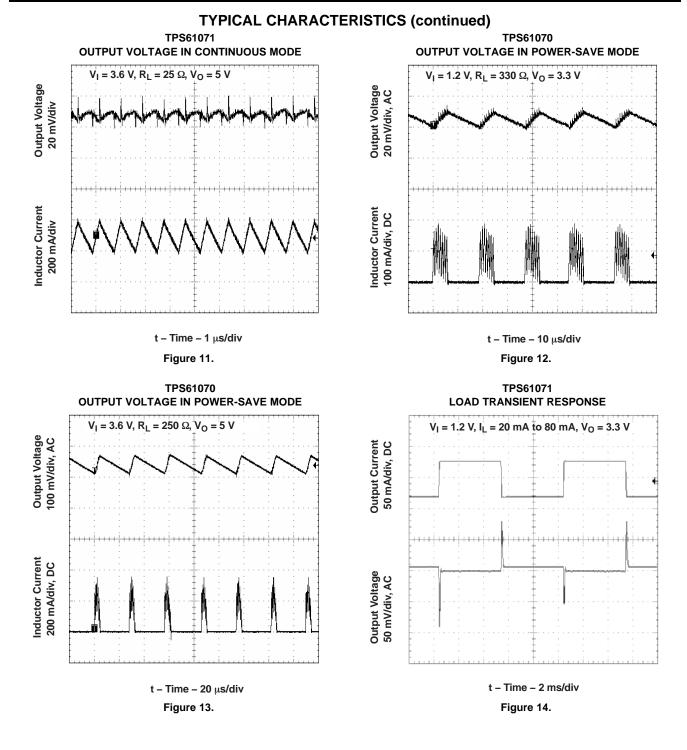


Texas

INSTRUMENTS



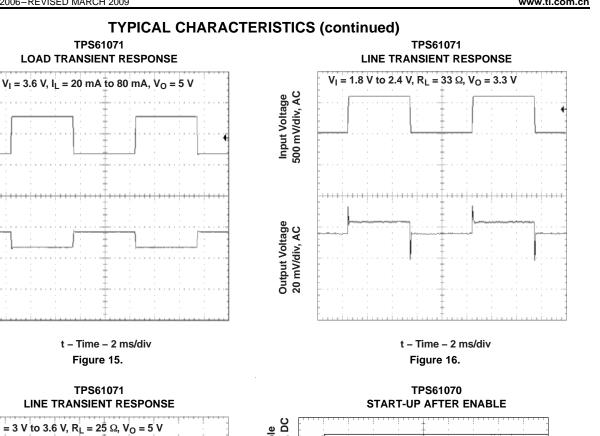
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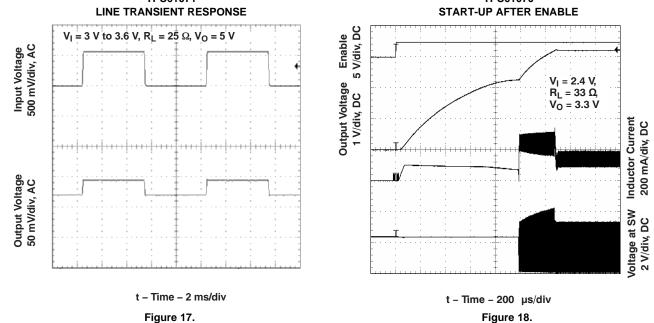


Output Current 50 mA/div, DC

Output Voltage 50 mV/div, AC

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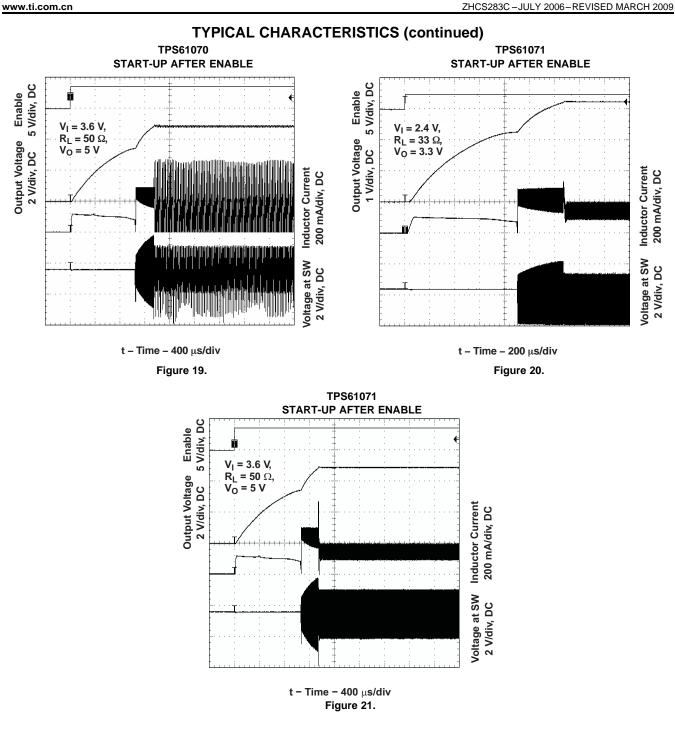






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INSTRUMENTS



DETAILED DESCRIPTION

CONTROLLER CIRCUIT

The controller circuit of the device is based on a fixed frequency multiple feedforward controller topology. Input voltage, output voltage, and voltage drop on the NMOS switch are monitored and forwarded to the regulator. So, changes in the operating conditions of the converter directly affect the duty cycle and must not take the indirect and slow way through the control loop and the error amplifier. The control loop, determined by the error amplifier, only has to handle small signal errors. The input for it is the feedback voltage on the FB pin. It is compared with the internal reference voltage to generate an accurate and stable output voltage.

The peak current of the NMOS switch is also sensed to limit the maximum current flowing through the switch and the inductor. The typical peak-current limit is set to 600 mA. An internal temperature sensor prevents the device from getting overheated in case of excessive power dissipation.

Synchronous Rectifier

The device integrates an N-channel and a P-channel MOSFET transistor to realize a synchronous rectifier. Because the commonly used discrete Schottky rectifier is replaced with a low $R_{DS(on)}$ PMOS switch, the power conversion efficiency reaches values above 90%. A special circuit is applied to disconnect the load from the input during shutdown of the converter. In conventional synchronous rectifier circuits, the backgate diode of the high-side PMOS is forward biased in shutdown and allows current flowing from the battery to the output. However, this device uses a special circuit which takes the cathode of the backgate diode of the high-side PMOS and disconnects it from the source when the regulator is not enabled (EN = low).

The benefit of this feature for the system design engineer is that the battery is not depleted during shutdown of the converter. No additional components must be added to the design to make sure that the battery is disconnected from the output of the converter.

Device Enable

The device is put into operation when EN is set high. It is put into a shutdown mode when EN is set to GND. In shutdown mode, the regulator stops switching, all internal control circuitry is switched off, and the load is isolated from the input (as described in the *Synchronous Rectifier Section*). This also means that the output voltage can drop below the input voltage during shutdown. During start-up of the converter, the duty cycle and the peak current are limited in order to avoid high-peak currents drawn from the battery.

Undervoltage Lockout

An undervoltage lockout function prevents the device from operating if the supply voltage on VBAT is lower than approximately 0.8 V. When in operation and the battery is being discharged, the device automatically enters the shutdown mode if the voltage on VBAT drops below approximately 0.8 V. This undervoltage lockout function is implemented in order to prevent the malfunctioning of the converter.

Soft Start and Short-Circuit Protection

When the device enables, the internal start-up cycle starts with the first step, the precharge phase. During precharge, the rectifying switch is turned on until the output capacitor is charged to a value close to the input voltage. The rectifying switch is current limited during this phase. The current limit increases with the output voltage. This circuit also limits the output current under short-circuit conditions at the output. Figure 22 shows the typical precharge current vs output voltage for specific input voltages:



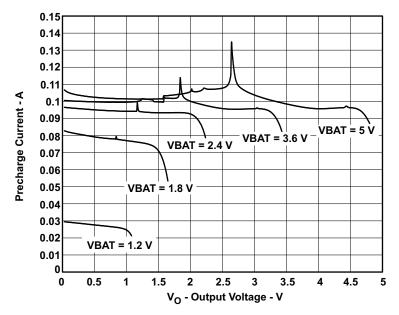


Figure 22. Precharge and Short-Circuit Current

After charging the output capacitor to the input voltage, the device starts switching. If the input voltage is below 1.8 V, the device works with a fixed duty cycle of 70% until the output voltage reaches 1.8 V. After that the duty cycle is set depending on the input output voltage ratio. Until the output voltage reaches its nominal value, the boost switch current limit is set to 50% of its nominal value to avoid high peak currents at the battery during start-up. As soon as the output voltage is reached, the regulator takes control, and the switch current limit is set back to 100%.

Power-Save Mode

The TPS61070 and TPS61073 are capable of operating in two different modes. At light loads, when the inductor current becomes zero, they automatically enter the power-save mode to improve efficiency. In the power-save mode, the converters only operate when the output voltage trips below a set threshold voltage. It ramps up the output voltage with one or several pulses and returns to the power-save mode once the output voltage exceeds the set threshold voltage. If output power demand increases and the inductor current no longer goes below zero, the device again enters the fixed PWM mode. In this mode, there is no difference between the PWM only versions TPS61071 and TPS61072 and the power-save mode enabled versions TPS61070 and TPS61073.



APPLICATION INFORMATION

DESIGN PROCEDURE

The TPS6107x dc/dc converters are intended for systems powered by a single-cell, up to triple-cell alkaline, NiCd, NiMH battery with a typical terminal voltage between 0.9 V and 5.5 V. They can also be used in systems powered by one-cell Li-ion or Li-polymer with a typical voltage between 2.5 V and 4.2 V. Additionally, any other voltage source with a typical output voltage between 0.9 V and 5.5 V can power systems where the TPS6107x is used. Due to the nature of boost converters, the output voltage regulation is only maintained when the input voltage applied is lower than the programmed output voltage.

Programming the Output Voltage

The output voltage of the TPS6107x dc/dc converter can be adjusted with an external resistor divider. The typical value of the voltage at the FB pin is 500 mV. The maximum recommended value for the output voltage is 5.5 V. The current through the resistive divider should be about 100 times greater than the current into the FB pin. The typical current into the FB pin is 0.01 μ A, and the voltage across R2 is typically 500 mV. Based on those two values, the recommended value for R2 should be lower than 500 k Ω , in order to set the divider current at 1 μ A or higher. Because of internal compensation circuitry, the value for this resistor should be in the range of 200 k Ω . From that, the value of resistor R1, depending on the needed output voltage (V_Ω), is calculated using Equation 1:

$$R1 = R2 \times \left(\frac{V_{O}}{V_{FB}} - 1\right) = 180 \text{ k}\Omega \times \left(\frac{V_{O}}{500 \text{ mV}} - 1\right)$$
(1)

For example, if an output voltage of 3.3 V is needed, a 1 M Ω resistor should be chosen for R1. If for any reason the value chosen for R2 is significantly lower than 200 k Ω , additional capacitance in parallel to R1 is recommended, if the device shows instable regulation of the output voltage. The required capacitance value is calculated using Equation 2:



Inductor Selection

A boost converter normally requires two main passive components for storing energy during the conversion. A boost inductor and a storage capacitor at the output are required. To select the boost inductor, it is recommended to keep the possible peak inductor current below the current limit threshold of the power switch in the chosen configuration. For example, the current limit threshold of the TPS6107x's switch is 600 mA. The highest peak current through the inductor and the switch depends on the output load, the input (V_{BAT}), and the output voltage (V_{OUT}). Estimation of the maximum average inductor current is done using Equation 3:

$$I_{L} = I_{O} \times \frac{VOUT}{VBAT \times 0.8}$$
(3)

For example, for an output current of 75 mA at 3.3 V, at least 340 mA of average current flows through the inductor at a minimum input voltage of 0.9 V.



The second parameter for choosing the inductor is the desired current ripple in the inductor. Normally, it is advisable to work with a ripple of less than 20% of the average inductor current. A smaller ripple reduces the magnetic hysteresis losses in the inductor, as well as output voltage ripple and EMI. But in the same way, regulation time rises at load changes. In addition, a larger inductor increases the total system costs. With these parameters, it is possible to calculate the value for the inductor by using Equation 4:

$$L = \frac{VBAT \times (VOUT - VBAT)}{\Delta I_{I} \times f \times VOUT}$$

(4)

Parameter *f* is the switching frequency and ΔI_L is the ripple current in the inductor, i.e., 40% ΔI_L . In this example, the desired inductor has the value of 4 µH. With this calculated value and the calculated currents, it is possible to choose a suitable inductor. In typical applications, a 4.7 µH inductance is recommended. The device has been optimized to operate with inductance values between 2.2 µH and 10 µH. Nevertheless, operation with higher inductance values may be possible in some applications. Detailed stability analysis is then recommended. Care must be taken because load transients and losses in the circuit can lead to higher currents as estimated in Equation 4. Also, the losses in the inductor caused by magnetic hysteresis losses and copper losses are a major parameter for total circuit efficiency.

The following inductor series from different suppliers have been used with the TPS6107x converters:

VENDOR	INDUCTOR SERIES
TDK	VLF3010
IDK	VLF4012
Month Electron 1	744031xxx
Wurth Elektronik	744042xxx
EPCOS	B82462-G4
Cooper Flootropics Technologies	SD18
Cooper Electronics Technologies	SD20
Taiyo Yuden	CB2016B xxx
	CB2518B xxx

Table 1. List of Inductors

Capacitor Selection

Input Capacitor

At least a 10 μ F input capacitor is recommended to improve transient behavior of the regulator and EMI behavior of the total power supply circuit. A ceramic capacitor or a tantalum capacitor with a 100-nF ceramic capacitor in parallel, placed close to the IC, is recommended.

Output Capacitor

The major parameter necessary to define the output capacitor is the maximum allowed output voltage ripple of the converter. This ripple is determined by two parameters of the capacitor, the capacitance and the ESR. It is possible to calculate the minimum capacitance needed for the defined ripple, supposing that the ESR is zero, by using Equation 5:

$$\mathbf{C}_{\min} = \frac{\mathbf{I}_{\mathbf{O}} \times (\mathsf{VOUT} - \mathsf{VBAT})}{f \times \Delta \mathsf{V} \times \mathsf{VOUT}}$$

(5)

Parameter *f* is the switching frequency and ΔV is the maximum allowed ripple.

With a chosen ripple voltage of 10 mV, a minimum capacitance of 4.5 μ F is needed. In this value range, ceramic capacitors are a good choice. The ESR and the additional ripple created are negligible. It is calculated using Equation 6:

$$\Delta V_{ESR} = I_O \times R_{ESR}$$

(6)



The total ripple is the sum of the ripple caused by the capacitance and the ripple caused by the ESR of the capacitor. Additional ripple is caused by load transients. This means that the output capacitor has to completely supply the load during the charging phase of the inductor. The value of the output capacitance depends on the speed of the load transients and the load current during the load change. With the calculated minimum value of 4.5 μ F and load transient considerations, the recommended output capacitance value is in a 10 μ F range.

Care must be taken on capacitance loss caused by derating due to the applied dc voltage and the frequency characteristic of the capacitor. For example, larger form factor capacitors (in 1206 size) have their self resonant frequencies in the same frequency range as the TPS6107x operating frequency. So the effective capacitance of the capacitors used may be significantly lower. Therefore, the recommendation is to use smaller capacitors in parallel instead of one larger capacitor.

Small Signal Stability

To analyze small signal stability in more detail, the small signal transfer function of the error amplifier and the regulator, which is given in Equation 7, can be used:

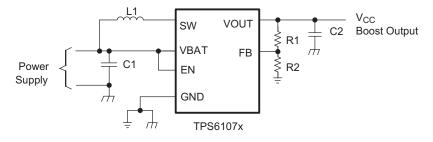
$$A_{(REG)} = \frac{d}{V_{(FB)}} = \frac{5 \times (R1 + R2)}{R2 \times (1 + i \times \omega \times 0.8 \,\mu\text{s})}$$
(7)

Layout Considerations

As for all switching power supplies, the layout is an important step in the design, especially at high-peak currents and high switching frequencies. If the layout is not carefully done, the regulator could show stability problems as well as EMI problems. Therefore, use wide and short traces for the main current path and for the power ground tracks. The input capacitor, output capacitor, and the inductor should be placed as close as possible to the IC. Use a common ground node for power ground and a different one for control ground to minimize the effects of ground noise. Connect these ground nodes at any place close to the ground pin of the IC.

The feedback divider should be placed as close as possible to the ground pin of the IC. To lay out the control ground, it is recommended to use short traces as well, separated from the power ground traces. This avoids ground shift problems, which can occur due to superimposition of power ground current and control ground current.

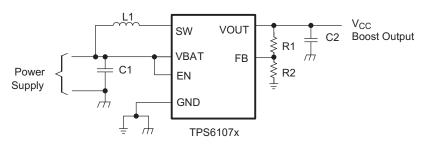
APPLICATION EXAMPLES



List of Components: U1 = TPS61070DDC L1 = 4.7 μ H Wurth Elektronik 744031004 C1 = 2 x 4.7 μ F, 0603, X7R/X5R Ceramic C2 = 2 x 4.7 μ F, 0603, X7R/X5R Ceramic

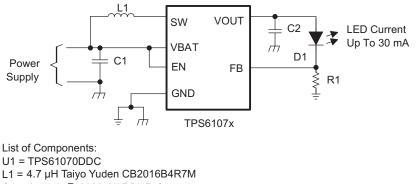
Figure 24. Power Supply Solution for Maximum Output Power Operating from a Single or Dual Alkaline Cell





List of Components: U1 = TPS61070DDC L1 = 4.7 μ H Taiyo Yuden CB2016B4R7M C1 = 1 x 4.7 μ F, 0603, X7R/X5R Ceramic C2 = 2 x 4.7 μ F, 0603, X7R/X5R Ceramic

Figure 25. Power Supply Solution Having Small Total Solution Size



C1 = 1 x 4.7 μ F, 0603, X7R/X5R Ceramic

C2 = 2 x 4.7 µF, 0603, X7R/X5R Ceramic

Figure 26. Power Supply Solution for Powering White LEDs in Lighting Applications

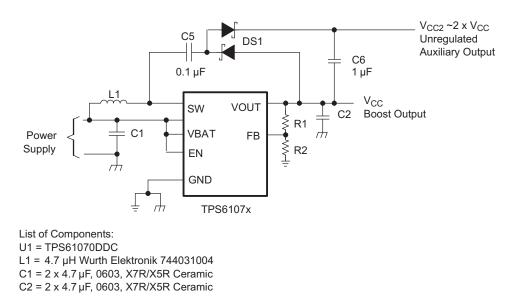
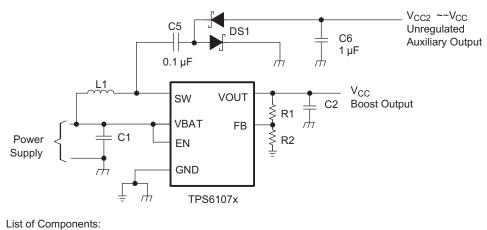


Figure 27. Power Supply Solution With Auxiliary Positive Output Voltage





List of Components. U1 = TPS61070DDC $L1 = 4.7 \mu H$ Wurth Elektronik 744031004 $C1 = 2 \times 4.7 \mu F$, 0603, X7R/X5R Ceramic $C2 = 2 \times 4.7 \mu F$, 0603, X7R/X5R Ceramic



THERMAL INFORMATION

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

Three basic approaches for enhancing thermal performance follow.

- Improving the power dissipation capability of the PCB design
- Improving the thermal coupling of the component to the PCB
- Introducing airflow in the system

The maximum recommended junction temperature (T_J) of the TPS6107x devices is 125°C. The thermal resistance of the 6-pin thin SOT package (DDC) is $R_{OJA} = 130$ °C/W. Specified regulator operation is assured to a maximum ambient temperature T_A of 85°C. Therefore, the maximum power dissipation is about 308 mW. More power can be dissipated if the maximum ambient temperature of the application is lower.

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_{A}}{R_{\theta JA}} = \frac{125^{\circ}C - 85^{\circ}C}{130^{\circ}C/W} = 308 \text{ mW}$$

(8)



PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS61070DDCR	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AUH
TPS61070DDCR.B	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AUH
TPS61070DDCRG4	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AUH
TPS61071DDCR	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AUJ
TPS61071DDCR.B	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AUJ
TPS61071DDCRG4	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AUJ
TPS61072DDCR	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BUM
TPS61072DDCR.B	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BUM
TPS61072DDCRG4	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BUM
TPS61072DDCRG4.B	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BUM
TPS61073DDCR	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BUN
TPS61073DDCR.B	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BUN

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.



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PACKAGE OPTION ADDENDUM

17-Jun-2025

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF TPS61071 :

• Automotive : TPS61071-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



Texas

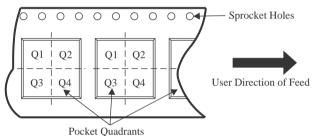
STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



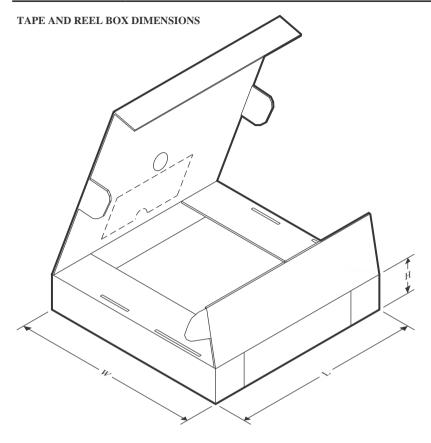
*All dimensions are nominal	<u> </u>											
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS61070DDCR	SOT-23- THIN	DDC	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS61071DDCR	SOT-23- THIN	DDC	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS61072DDCR	SOT-23- THIN	DDC	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS61072DDCRG4	SOT-23- THIN	DDC	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS61073DDCR	SOT-23- THIN	DDC	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3



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PACKAGE MATERIALS INFORMATION

18-Jun-2025



*All dimensions are nominal	
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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS61070DDCR	SOT-23-THIN	DDC	6	3000	200.0	183.0	25.0
TPS61071DDCR	SOT-23-THIN	DDC	6	3000	200.0	183.0	25.0
TPS61072DDCR	SOT-23-THIN	DDC	6	3000	200.0	183.0	25.0
TPS61072DDCRG4	SOT-23-THIN	DDC	6	3000	200.0	183.0	25.0
TPS61073DDCR	SOT-23-THIN	DDC	6	3000	200.0	183.0	25.0

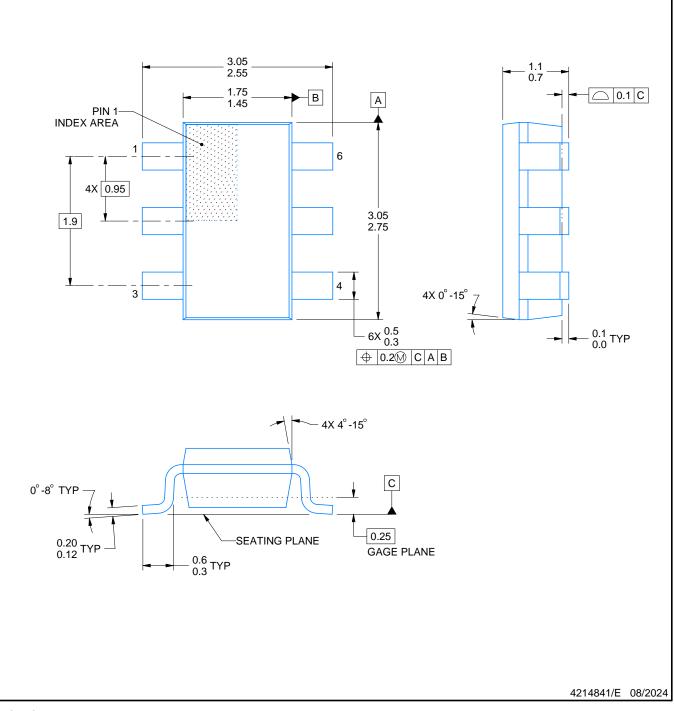
DDC0006A



PACKAGE OUTLINE

SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-193.

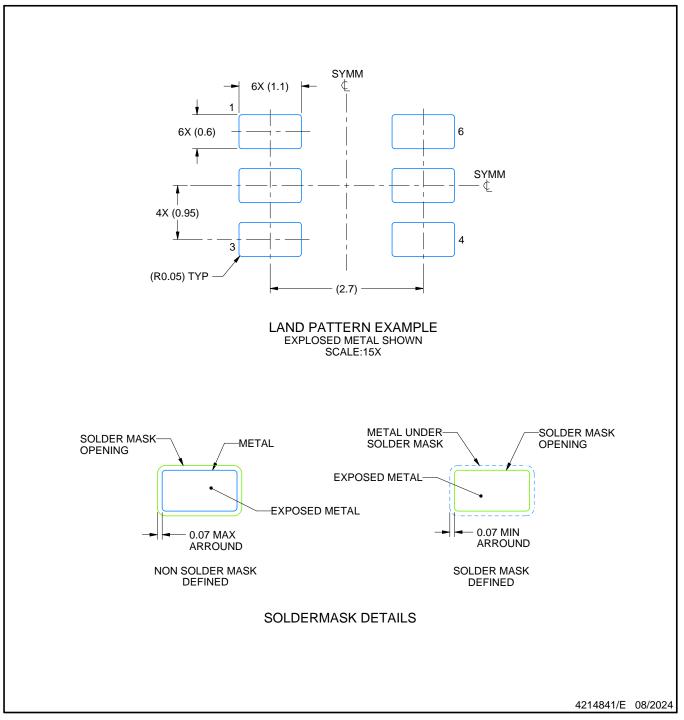


DDC0006A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

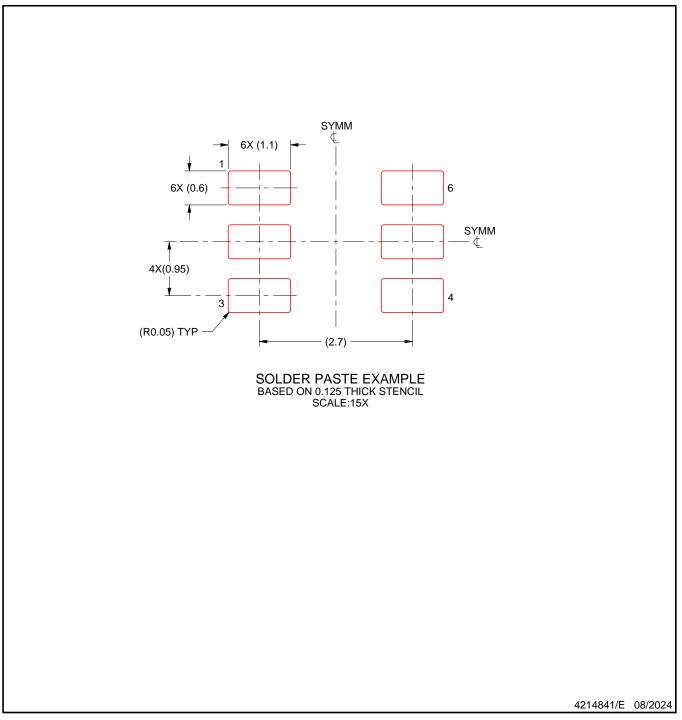


DDC0006A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations. 7. Board assembly site may have different recommendations for stencil design.



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